

PNP Digital transistors

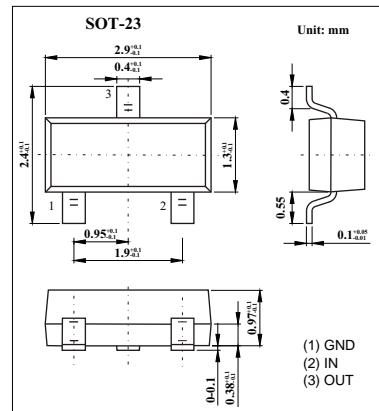
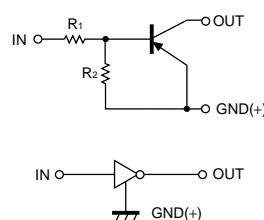
KTA143ZKA

Features

PNP digital transistor (Built-in resistor types)

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors

Only the on/off conditions need to be set for operation, making device design easy.



Absolute Maximum Ratings Ta = 25

Parameter	Symbol	Rating	Unit
Supply voltage	Vcc	-50	V
Input voltage	Vin	-30~+5	V
Output current	Io	-100	mA
	IC(Max.)	-100	
Power dissipation	Pd	200	mW
Junction temperature	Tj	150	
Storage temperature	Tstg	-55~+150	

Electrical Characteristics Ta = 25

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Input voltage	Vi(off)	Vcc=-5V, Io=-100 μA			-0.5	V
	Vi(on)	Vo=-0.3V, Io=-5mA	-1.3			V
Output voltage	Vo(on)	Io/Ii=-5mA/-0.25mA		-0.1	-0.3	V
Input current	Ii	Vi=-5V			-1.8	mA
Output current	Io(off)	Vcc=-50V, Vi=0V			-0.5	μA
DC current gain	Gi	Vo=-5V, Io=-10mA	80			
Input resistance	R1	-	3.29	4.7	6.11	k
Resistance ratio	R2/R1	-	8	10	12	k
Transition frequency	ft	Vce=-10V, Ie=5mA, f=100MHz		250		MHz

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Typical Characteristics

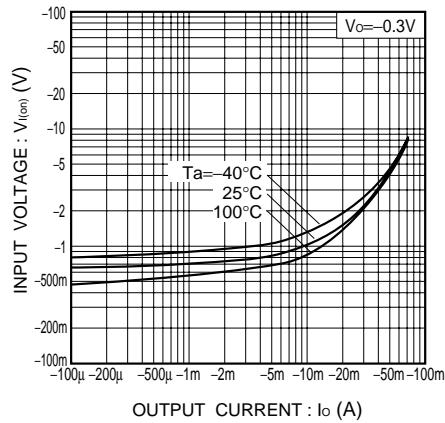


Fig.1 Input voltage vs. output current
(ON characteristics)

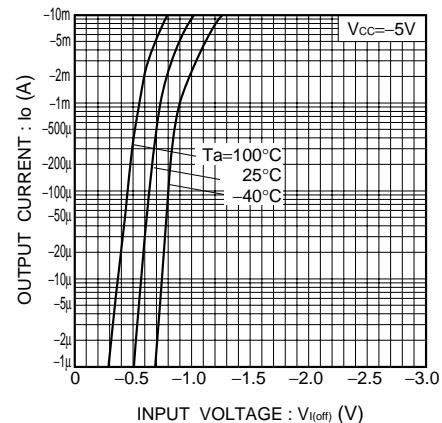


Fig.2 Output current vs. input voltage
(OFF characteristics)

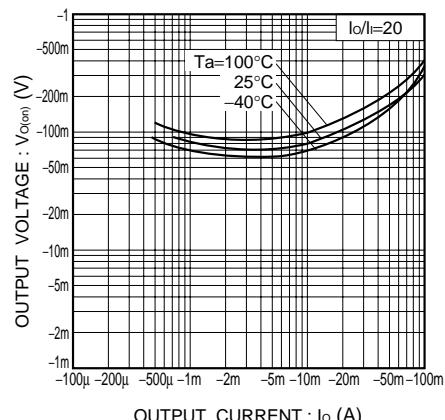


Fig.4 Output voltage vs. output current

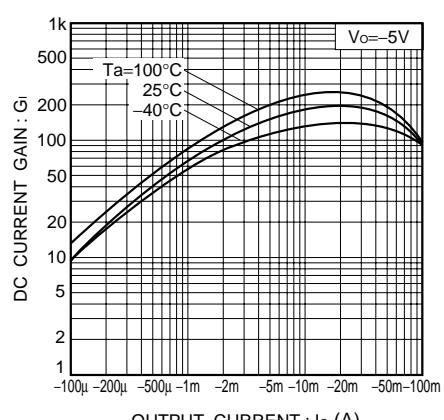


Fig.3 DC current gain vs. output current